SCHEMATIC SYMBOL	DESCRIPTION	B&K PART No.					
SWITCHES							
S105 S106, VR109, VR110	Rotary Switch (MODE)						
S101, S103, S107, S108	Slide Switch (3 POS)084	-022-9-001					
S109	Slide Switch (SLOPE)084	-022-9-002					
MISCELLANEOUS							
PL101, PL102	Bezel 380 Bezel Retaining Nut 653 Case 272 Fuse, 1 Amp, 3 AG 191 Graticule 380 Graticule Filter, Green 380 Knob, (VOLTS/CM, SWEEP TIME, MO Grey Grey .751 Knob, Grey .751 Knob, (STABILITY), Grey .751 Knob, Black .751 Knob, (V POSITION), Grey .751 Lamp, Scale Illumination .400 Transformer, Power .066	3-011-9-001 2-082-9-001 1-251-3-001 0-137-9-002 0-137-9-003 DE) 1-077-9-001 1-077-9-002 1-077-9-003 1-077-9-001 1-091-9-001					
NOTE: Standard Value resistors are not listed. Values may be obtained from the Schematic Diagram.							
SPECIFY SERIAL NO. WHEN ORDERING REPLACEMENT PARTS							

B & K MODEL 1470 PARTS LIST

488-119-9-002

HORIZONTAL AMP/SWEEP P.C. BOARD

SCHEMATIC SYMBOL	DESCRIPTION CONTROL C	B & K PART No.
~	RESISTORS & CONTROLS	
R46	22KΩ, 2W, 5%, Metal Film Resistor01	
R49	22KΩ, 3W, 5%, Metal Film Resistor01	
R57, R58	15KΩ, 2W, 5%, Metal Film Resistor01	
R62	680Ω, 2W, 5%, Metal Film Resistor01	
R67	470Ω, 3W, 5% Metal Film Resistor01	
VR1	2.2KΩ, 0.15W, 25%, Trim Pot00	
VR2, VR3, VR10	47 K Ω , 0.15W, 25%, Trim Pot00	
VR4, VR5	10 K Ω , 0.15 W, 25% , Trim Pot00	
VR6, VR7	1K Ω , 0.15W, 25%, Trim Pot00	_
VR8	330Ω, 0.15W, 25%, Trim Pot00	
VR9	22 K Ω , 0.15 W, 25% , Trim Pot00	08-163-9-010
	CAPACITORS	
C2	1μfd, 50V, Non-Polarlytic03	34-003-9-002
C10, C11	10μfd, 25V, Electrolytic Capacitor03	22-086-9-005
C14	100μfd, 16V, Electrolytic Capacitor0	22-073-9-002
C27, C31	470 μfd, 16V, Electrolytic Capacitor0	22-073-9-003
C28	100μfd, 50V, Electrolytic Capacitor0	22-073-9-007
C29, C30, C32	220μfd, 50V, Electrolytic Capacitor0	22-073-9-006
	DIODES & TRANSISTORS	
D1, D3, D4-D6	Diode, Silicon, 1S15551	51-028-9-007
D2	Diode, Silicon 1N601	50-001-9-005
D7, D10	Zener Diode, ZB1-61	
D8	Diode, Silicon, 1S18501	51-028-9-002
D9	Diode, Silicon, 1S1850R1	51-028-9-003
D11	Diode, Silicon, 10D101	51-028-9-006
Q1-Q4, Q6-Q11		
Q16, Q17, Q21, Q22	Transistor, Silicon, NPN, 2SC458-C1	76-016-9-001
Q5, Q14	Transistor, Field Effect, 2SK19-G (IGSS)1	82-021-9-001
Q12, Q18, Q19	Transistor, Silicon, NPN, 2SC1012-A1	76-028-9-008
Q13	Transistor, Field Effect, 2SK19-Y (IGSS)1	82-021-9-002
Q15	Transistor, Silicon, NPN, 2SC9841	
Q20	Transistor, Silicon, NPN, 2SC9711	76-028-9-007

COMPOSITE 499-043-9-00

SCHEMATIC SYMBOL	DESCRIPTION	B & K PART No	SCHEMATIC SYMBOL	DESCRIPTION PART	
				VERTICAL ATTENUATORS	
CH1 & C	H 2 VERTICAL AMPLIFIER P.O	C. BOARD	S-102/VR102 S-104/VR105	"VOLTS/CM" Switch & Variable Control (CH1 & CH2)083-137-9	9-001
	RESISTORS & CONTROLS		R101, R107	900KΩ, ½W, 1%, Deposited Carbon Resistor	2-004
R53, R54	$8K\Omega$, 1W, 5%, Metal Film Resis		D100 D100)-9U%
R60, R61	2.7KΩ, 3W, 5%, Metal Film Res		R102, R108	111KΩ, ½W, 1%, Deposited Carbon Resistor002-001-9	9-021
VR1, VR5	68 K Ω , 0.15W, 25%, Trim Pot		R103, R109	990KΩ, ½W, 1%, Deposited Carbon	
VR2, VR6	22KΩ, 0.15W, 25%, Trim Pot			Resistor002-102-8	3-994
VR3-VR7	10KΩ, 0.15W, 25%, Trim Pot		R104, R110	10.1KΩ, ½W, 1%, Deposited Carbon Resistor	0-024
VR4	150Ω, 0.15W, 25%, Trim Pot		DIAF DIII		7-02-9
VR8	330Ω, 0.15W, 25%, Trim Pot	008-155-9-006	R105, R111	999KΩ, ½W, 1%, Deposited Carbon Resistor002-001-6	9-028
G0 G0 GW G0	CAPACITORS & TRIMMERS		R106, R112	1K\(\Omega\), \(\frac{1}{2}\)W, \(1\)%, Deposited Carbon Resistor002-102-5	3-102
C2, C3, C7, C8 C11	100μ fd, 16V, Electrolytic Capaci 47 μ fd, 50V, Electrolytic Capacit		R116, R117	1MΩ, ½W, 1%, Deposited Carbon Resistor	3-105
C15, C25	$22\mu\mathrm{fd}$, 50V, Electrolytic Capacite			MAIN CHASSIS	
C16	22μ fd, 250V, Electrolytic Capaci	tor021-038-9-002		RESISTORS & CONTROLS	
C17, C18	47μ fd, 16V, Electrolytic Capacite	or022-090-9-003	VR101, VR103	5KΩ, Carbon Pot, "DC BAL"008-174-	9-003
TC1, TC3	10pfd, Trimmer Capacitor		VR-104, VR106	5KΩ. Carbon Pot, "V POS"008-174-9	
TC2, TC4	20pfd, Trimmer Capacitor		VR107	100KΩ, Carbon Pot, "TRIG LEVEL"008-174-	
TC5, TC6	70pfd, Trimmer Capacitor	028-025-9-002	VR108	100KΩ, Carbon Pot, "STABILITY"008-174-	
	COILS & CHOKES		VR112	250ΚΩ, 0.2W, 20%, Carbon Pot, "ASTIG"008-169-	
L1, L2	20μH, Peaking Coil	041-053-9-001	VR113	1MΩ, 0.25W, 20%, Carbon Pot, "INTENSITY"008-163-	9-003
	DIODES & TRANSISTORS		VR114	500KΩ, 0.25W, 20%, Carbon Pot,	
D1,-D10	Diode, Silicon, 1S1555		• • • • • • • • • • • • • • • • • • • •	"FOCUS"008-169-	9-004
D11, D12	Diode, Germanium, 1N60		VR115/S112	100Ω, 0.25W, 20%, Carbon Pot,	0.015
Q1, Q10	Transistor, Field Effect, 2SK19- (IGSS)			"ILLUM"	9-019
Q2-Q5,	Transistor, Field Effect, 2SK30			CAPACITORS & TRIMMERS	
Q11-Q14	Transistor, Field Effect, 25K50	0102-014-5-000	C126	0.5\(\psi\)fd x 5, 1.5KV, 5 Section Oil Capacitor	9-002
Q6, Q7, Q15,) Q16, Q19,			C127	47ufd, 250V, 3 Section Electrolytic Capacitor	0-001
Q22, Q23, / Q30, Q33, / Q36, Q39	Transistor, Silicon, NPN, 2SC4	58-C176-016-9-001 ,	TC101, TC103, TC105, TC107, TC109, TC111	50 pfd, Trimmer Capacitor	
Q8, Q9, Q17, Q18, Q20, Q21, Q28, Q2 9	Transistor, Silicon, NPN, 2SC5	35-B176-036-9-001	TC102, TC104,) TC106, TC108, \ TC110,TC112 TC113, TC114	10pfd, Trimmer Capacitor028-020-	9-004
Q24, Q25	Transistor Silicon, NPN, 2SC2	34-H176-028-9-005		DIODES, TRANSISTORS & TUBES	
Q26, Q27	Transistor, Silicon, NPN, 2SC9		D101, D102	Diode, Silicon ED01-04151-033-	9-001
Q34, Q35	Transistor, Silicon, PNP, 2SA5		D103, D104	Diode, Silicon S-05-08151-033-	9-002
• • •					

Transistor Silicon, NPN, 2SC1012-A..176-028-9-008

Q40

CRT 5DEPI (S)230-003-9-001

